

# **AP3407B**

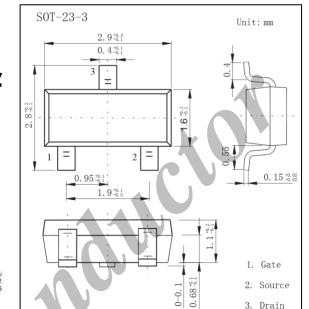
# **30V P-Channel Enhancement Mode MOSFET**

# **General Description**

AP3407B combines advanced MOSFET technology with a low resistance package to provide extremely low RDS(ON). This device is most suitable to load-switch or PWM applications.

# G

Top View



# **Applications**

- DC/DC converter for portable devices
- Load switch

## **Product Summary**

 $V_{DS}(V)$ -30V

-4.1A  $I_D$ 

 $R_{DS(ON)}$  (at  $V_{GS} = -10V$ )  $< 52 m\Omega$ 

RDS(ON) (at  $V_{GS} = -4.5V$ )  $< 87 \text{m}\Omega$ 



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3. Drain

# Absolute Maximum Ratings (Ta = 25°C unless otherwise noted)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	VDS	-30	V	
Gate-Source Voltage	Vgs	±20	v	
Continuous Drain Current Ta = 25 ℃	ID	-4.1		
Ta = 70℃	טו	-3.5	A	
Pulsed Drain Current	Ірм	-20		
Power Dissipation Ta = 25℃	₽D	1.4	W	
Ta = 70 ℃	PU	1		
Thermal Resistance.Junction- to-Ambient t ≤10s	RthJA	90		
Steady State	Kuisa	125	°C/W	
Thermal Resistance.Junction- to-Lead	RthJL	60		
Junction Temperature	Tı	150	℃	
Storage Temperature Range	Tstg	-55 to 150		



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# • Electrical Characteristics (Ta = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	Voss	ID=-250 μ A, VGS=0V	-30			V
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-24V, V <sub>GS</sub> =0V			-1	^
		Vps=-24V, Vgs=0V, TJ=55°C			-5	μА
Gate-Body leakage current	Igss	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA
Gate Threshold Voltage	VGS(th)	VDS=VGS ID=-250 μ A	-1	-1.8	-3	V
Static Drain-Source On-Resistance	Rds(on)	Vgs=-10V, Ip=-4.1A		40.5	52	mΩ
		Vgs=-10V, Ip=-4.A TJ=125℃		57	73	
		Vgs=-4.5V, Ip=-3A	7	64	87	
On state drain current	Id(on)	Vgs=-4.5V, Vps=-5V	-10			Α
Forward Transconductance	<b>g</b> FS	Vps=-5V, Ip=-4A	5.5	8.2		S
Input Capacitance	Ciss	Vgs=0V, Vps=-15V, f=1MHz		700		
Output Capacitance	Coss			120		pF
Reverse Transfer Capacitance	Crss			75		
Gate resistance	Rg	Vgs=0V, Vps=0V, f=1MHz		10		Ω
Total Gate Charge	Qg			14.3		
Gate Source Charge	Qgs	Vgs=-4.5V, Vps=-15V, lp=-4A		7		nC
Gate Drain Charge	Qgd			3.1		
Turn-On DelayTime	td(on)	Vgs=-10V, Vds=-15V, RL=3.6 Ω ,Rgen=3 Ω		8.6		
Turn-On Rise Time	tr			5		
Turn-Off DelayTime	td(off)			28.2		ns
Turn-Off Fall Time	tr			13.5		
Body Diode Reverse Recovery Time	trr	I <sub>F</sub> =-4A, dı/dt=100A/ μ s		27		
Body Diode Reverse Recovery Charge	Qrr			15		nC
Maximum Body-Diode Continuous Current	Is				-2.2	Α
Diode Forward Voltage	Vsp	Is=-1A,VGS=0V		-0.77	-1	V

# Ordering Information

Ordering Part Number	Package	MOQ
AP3407B	SOT23-3	3,000 pcs / reel

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# • Typical Characteristics

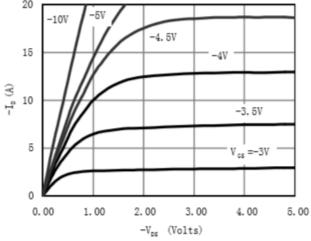


Figure 1: On-Region Characteristics

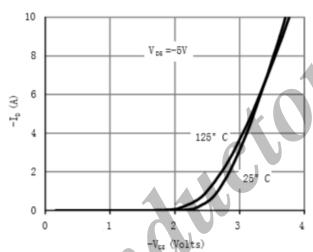


Figure 2: Transfer Characteristics

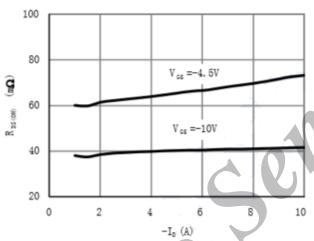


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

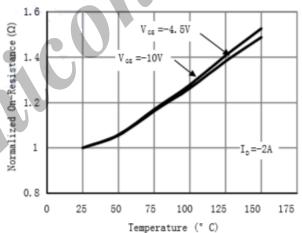


Figure 4: On-Resistance vs. Junction Temperature

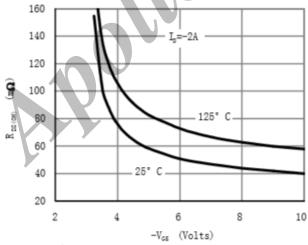


Figure 5: On-Resistance vs. Gate-Source Voltage

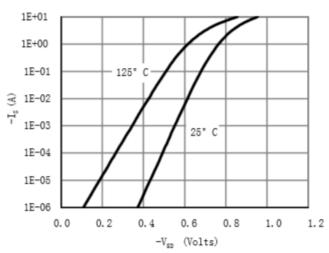


Figure 6: Body-Diode Characteristics



# • Typical Characteristics

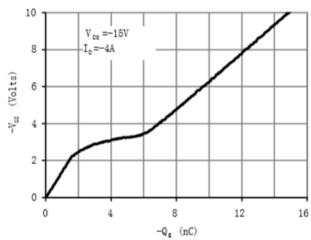


Figure 7: Gate-Charge Characteristics

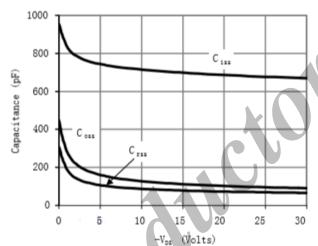


Figure 8: Capacitance Characteristics

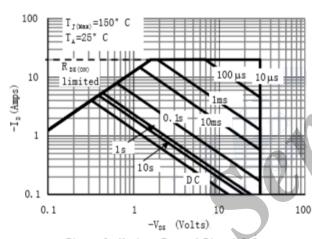


Figure 9: Maximum Forward Biased Safe Operating Area (Note E)

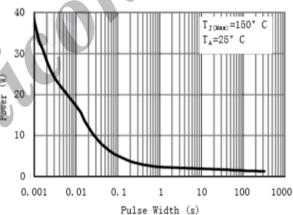


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note E)

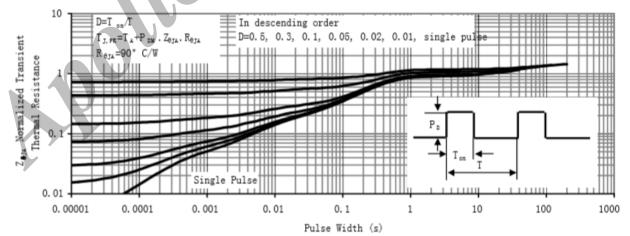


Figure 11: Normalized Maximum Transient Thermal Impedance

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